

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

BERNARD BEAUMONT, ET AL.

For: **Method For Producing By Vapour-Phase
Epitaxy a Gallium Nitride Film With Low
Defect Density**

Mail Stop Patent Application
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Dear Sir:

Please enter the following preliminary amendment for the present patent application.

In the Specification:

After the title, please insert the following:

--The present patent application is a non-provisional application of International Application No.
FR2003/002340, filed July 24, 2003.--

Respectfully submitted,

Blakely, Sokoloff, Taylor & Zafman LLP

Dated:

1/21/05


Eric S. Hyman, Reg. No. 30,139

12400 Wilshire Boulevard, 7th Floor
Los Angeles, CA 90025
Telephone: (310) 207-3800